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Supporting information for:

In situ TEM Tracking Sodium Migration in TiS₂

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Figure S1. Electron diffraction pattern of (a) pristine TiS₂ and (b) simulated TiS₂ single crystal. Simulated pattern is calculated by theoretical atomistic model (PDF#15-0853, a=3.397 Å, b=3.397 Å, c=5.691 Å).



Figure S2. The electron diffraction pattern of Na₂O/ Na probe.



Figure S3. Nanometer-sized domains generate after sodium inserted into TiS2. The angles of domains are 38.6±6.6 degree, compared with the pristine 33.4 degree. The change results from the in-homogenous lattice expansion during sodiation.

In order to calculate the average angle of sodiated TiS_2 domains, 740 domains were measured. The measurement was based on a frame of TEM image at 5 min.



Figure S4. TiS₂ nanosheet exposed under electron beam irradiation.

Under long time irradiation in TEM column environment, TiS₂ remains its layered structure. TiS₂ nanosheets were intentionally exposed under electron beam in TEM column environment. The dose rate was kept at 2.0×10^4 e Å⁻² s⁻¹. After 20 mins exposure under electron beam (total dose 2.40×10^7 e Å⁻²), no lattice expansion observed. As our in-situ sodiation experiments were carried out in less than 10 mins at a dose rate 4.7×10^3 e Å⁻² s⁻¹ (total dose is 2.8×10^6 e Å⁻² that is far below the tested one), the effects of these environmental factors in column (beam damage effects, possible oxygen and water vapor, heating etc.) can be ruled out.



Figure S5. The inverse Fast Fourier Transformation (iFFT) images to show boundaries between different phases. The iFFT images are acquired only including superstructure FFT spot of TEM images to judge the position of the boundary.



Figure S6. Na₂S in fully sodiated TiS₂ discharged to 0 V. (a) A TEM image of the fully sodiated TiS₂. (b) An enlarged view of showing the spacing between lattice is 3.213 Å, corresponding to the Na₂S (200) plane (PDF#23-0441).



Figure S7. Superstructure of Na-intercalated TiS₂. (a) FFT pattern of the TEM image at 28 s during sodiation (see also Figure 4b). (b) A simulated electron diffraction pattern of pristine TiS₂ single crystal. (c) A simulated electron diffraction pattern of Na_{0.25}TiS₂.



Figure S8. Structure of *ex situ* **electrochemical Na-intercalated TiS₂.** (a) The first galvanostatic discharge curve of Na-TiS₂ half battery. The x-axis indicates the mole ratio (*x*) of Na in the Na_xTiS₂ composition which is calculated from discharge capacity of the battery based on the Na/TiS₂ theoretical capacity. (b) Charge-discharge curves with 100 cycles. (c) The SAED pattern of TiS₂ electrode discharged to the end of first platform (2.1 V) in a half coin cell. The orange dash rhombus shows the basic geometry of original TiS₂ crystal. (d) Elements distribution maps of a TiS₂ single powder from battery electrode discharged to 2.1 V.

On the first galvanostatic discharge curve of Na-TiS₂ half battery, the discharge profile contains a platform at low Na concentration, which corresponds to an intercalation reaction with Na_xTiS₂ generation. From the SAED pattern of TiS₂ discharged to 2.1 V, although the sodium ion has intercalated into TiS₂ nanosheets based on the elements distribution maps, there is no 2×2 superstructure diffraction spots (Na_{0.25}TiS₂) observed. As for Na-TiS₂ battery, the first coulombic efficiency is 76.6% with 44.6 mAh g⁻¹ capacity loss. Besides, the capacity decreases in the following cycles and after 100 cycles the discharge capacity decreases to 115.0 mAh g⁻¹ from the first 190.5 mAh g⁻¹. The degraded capacities may be related to the irreversible structure fracture with the formation of nanosized domains (in Figure 2) of TiS₂ during soidum insertion. Moreover, the sodiation process undergoes a large volume expansion, leading to the formation of defects and fracture in the active material TiS₂ and losing contact with the electronic binder, which also contributes to the capacity decay.

Movie S1: (corresponding to Figure. 2) This video is made up of series of HRTEM images and shows the structural evolution of TiS_2 .

Movie S2: (corresponding to Figure. 3) This video shows the phase propagation of conversion region and 2×2 superstructure region in TiS₂.